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Team Nexperia

PHK04P02T

P-channel vertical D-MOS logic level FET

Rev. 02 — 14 December 2010

Product data sheet

1. Product profile

1.1 General description

Logic level P-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using vertical D-MOS technology. This product is designed and qualified for use in computing, communications, consumer and industrial applications only.

1.2 Features and benefits

- Suitable for high frequency applications due to fast switching characteristics
- Suitable for logic level gate drive sources
- Suitable for very low gate drive sources voltage

1.3 Applications

- Battery powered applications
- High-speed digital interfaces

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{DS}	drain-source voltage	T _j ≥ 25 °C; T _j ≤ 150 °C	-	-	-16	V
I _D	drain current	T _{sp} = 25 °C	-	-	-4.6 6	A
P _{tot}	total power dissipation		-	-	5	W
Static characteristics						
R _{DSon}	drain-source on-state resistance	V _{GS} = -2.5 V; I _D = -1 A; T _j = 25 °C	-	117	150	mΩ
		V _{GS} = -4.5 V; I _D = -1 A; T _j = 25 °C	-	80	120	mΩ
Dynamic characteristics						
Q _{GD}	gate-drain charge	V _{GS} = -4.5 V; I _D = -1 A; V _{DS} = -10 V; T _j = 25 °C	-	1.83	-	nC



2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	<p>SOT96-1 (SO8)</p>	<p>001aaa025</p>
2	S	source		
3	S	source		
4	G	gate		
5	D	drain		
6	D	drain		
7	D	drain		
8	D	drain		

3. Ordering information

Table 3. Ordering information

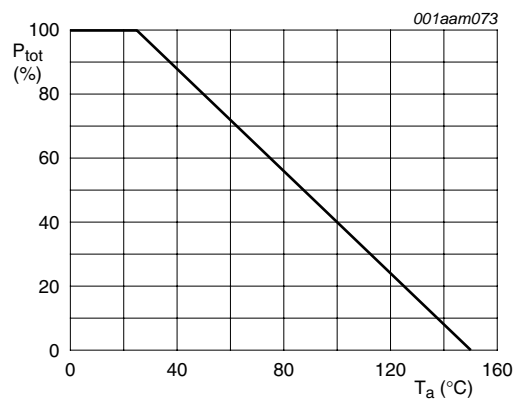
Type number	Package		
	Name	Description	Version
PHK04P02T	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1

4. Limiting values

Table 4. Limiting values

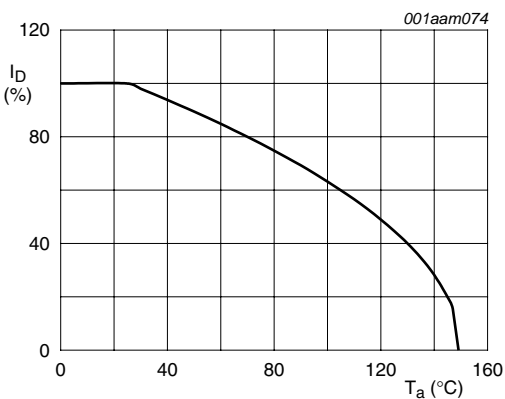
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25\text{ °C}$; $T_j \leq 150\text{ °C}$	-	-16	V
V_{DGR}	drain-gate voltage	$R_{GS} = 20\text{ k}\Omega$	-	-16	V
V_{GS}	gate-source voltage		-8	8	V
I_D	drain current	$T_{sp} = 100\text{ °C}$	-	-1.87	A
		$T_{sp} = 25\text{ °C}$	-	-4.66	A
I_{DM}	peak drain current	$T_{sp} = 25\text{ °C}$; pulsed	-	-26.4	A
P_{tot}	total power dissipation	$T_{sp} = 25\text{ °C}$	-	5	W
		$T_{sp} = 100\text{ °C}$	-	2	W
T_{stg}	storage temperature		-55	150	°C
T_j	junction temperature		-55	150	°C
Source-drain diode					
I_S	source current	$T_{sp} = 25\text{ °C}$	-	-4.66	A
I_{SM}	peak source current	$T_{sp} = 25\text{ °C}$; pulsed; $t_p \leq 5\text{ s}$	-	-26	A



$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

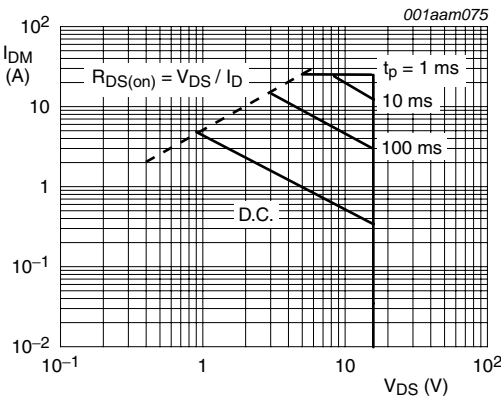
Fig 1. Normalised power dissipation as a function of ambient temperature



$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100\%$$

$V_{GS} \leq -10\text{ V}$

Fig 2. Normalized continuous drain current as a function of ambient temperature



$T_{sp} = 25^{\circ}C$; I_{DM} is single pulse

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	mounted on metal clad substrate	-	25	-	K/W

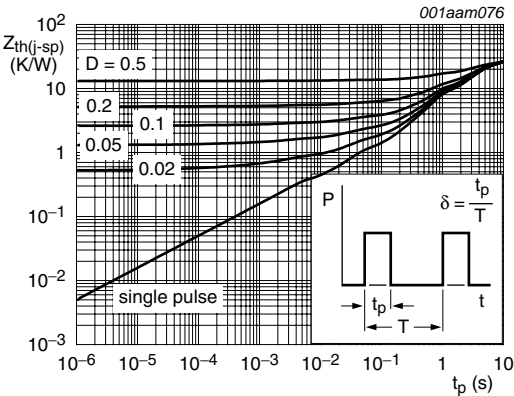


Fig 4. Transient thermal impedance from junction to solder point as a function of pulse duration

6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V _{(BR)DSS}	drain-source breakdown voltage	I _D = -10 μA; V _{GS} = 0 V; T _j = 25 °C	-16	-	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = -1 mA; V _{DS} = V _{GS} ; T _j = 25 °C	-0.4	-0.6	-	V
		I _D = -1 mA; V _{DS} = V _{GS} ; T _j = 150 °C	-0.1	-	-	V
I _{DSS}	drain leakage current	V _{DS} = -13 V; V _{GS} = 0 V; T _j = 25 °C	-	-50	-100	nA
		V _{DS} = -13 V; V _{GS} = 0 V; T _j = 150 °C	-	-13	-100	μA
I _{GSS}	gate leakage current	V _{GS} = 8 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA
		V _{GS} = -8 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = -2.5 V; I _D = -1 A; T _j = 25 °C	-	117	150	mΩ
		V _{GS} = -2.5 V; I _D = -1 A; T _j = 150 °C	-	175	230	mΩ
		V _{GS} = -1.8 V; I _D = -0.5 A; T _j = 25 °C	-	140	180	mΩ
		V _{GS} = -4.5 V; I _D = -1 A; T _j = 25 °C	-	80	120	mΩ
Dynamic characteristics						
Q _{G(tot)}	total gate charge	I _D = -1 A; V _{DS} = -10 V; V _{GS} = -4.5 V; T _j = 25 °C	-	7.2	-	nC
Q _{GS}	gate-source charge		-	1.7	-	nC
Q _{GD}	gate-drain charge		-	1.83	-	nC
C _{iss}	input capacitance	V _{DS} = -13 V; V _{GS} = 0 V; f = 1 MHz; T _j = 25 °C	-	528	-	pF
C _{oss}	output capacitance		-	200	-	pF
C _{rss}	reverse transfer capacitance		-	57	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = -10 V; R _L = 10 Ω; V _{GS} = -8 V; R _{G(ext)} = 6 Ω; T _j = 25 °C; I _D = -1 A	-	2	-	ns
t _r	rise time		-	4.5	-	ns
t _{d(off)}	turn-off delay time		-	45	-	ns
t _f	fall time		-	20	-	ns
g _{fs}	transfer conductance	V _{DS} = -13 V; I _D = -1 A; T _j = 25 °C	1.5	4.5	-	S
Source-drain diode						
V _{SD}	source-drain voltage	I _S = -0.62 A; V _{GS} = 0 V; T _j = 25 °C	-	-0.62	-1.3	V
t _{rr}	reverse recovery time	I _S = -0.5 A; di _S /dt = -100 A/μs; V _{GS} = 0 V; V _{DS} = -12.8 V; T _j = 25 °C	-	75	-	ns
Q _r	recovered charge		-	69	-	nC

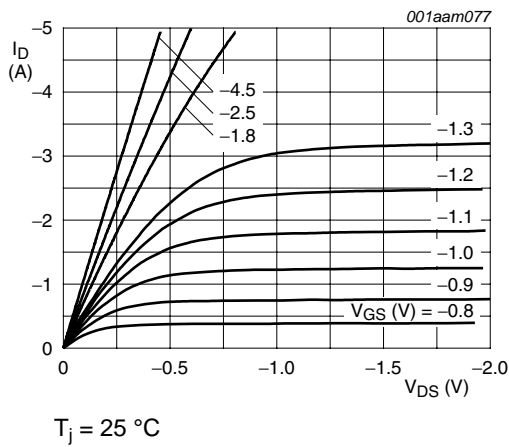


Fig 5. Output characteristics: drain current as a function of drain-source voltage; typical values

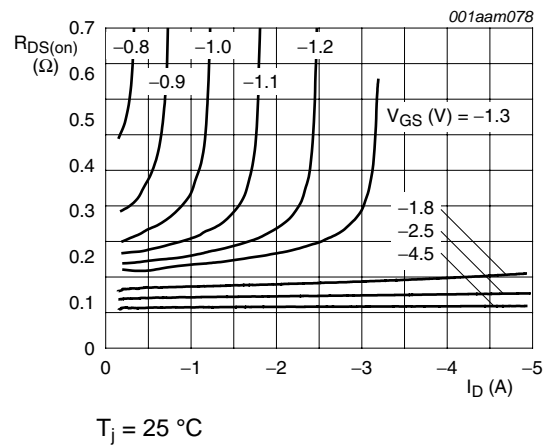


Fig 6. Drain-source on-state resistance as a function of drain current; typical values

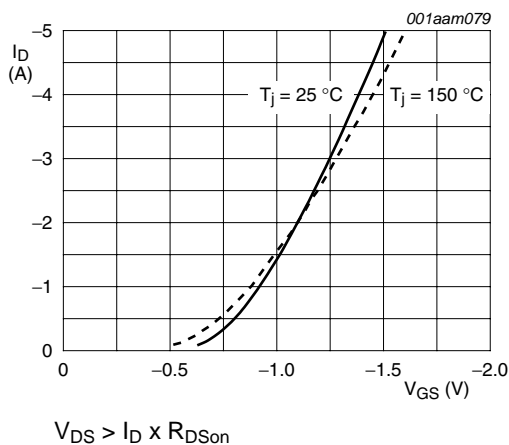


Fig 7. Transfer characteristics: drain current as a function of gate-source voltage; typical values

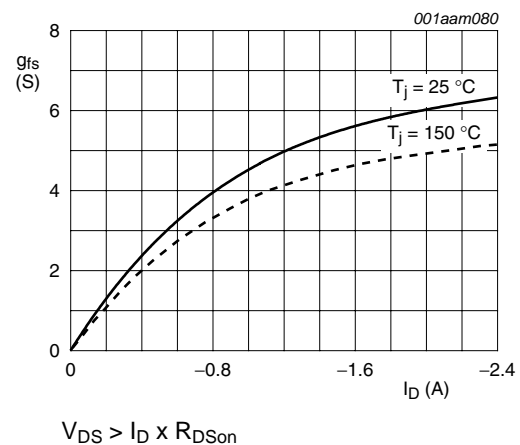


Fig 8. Forward transconductance as a function of drain current; typical values

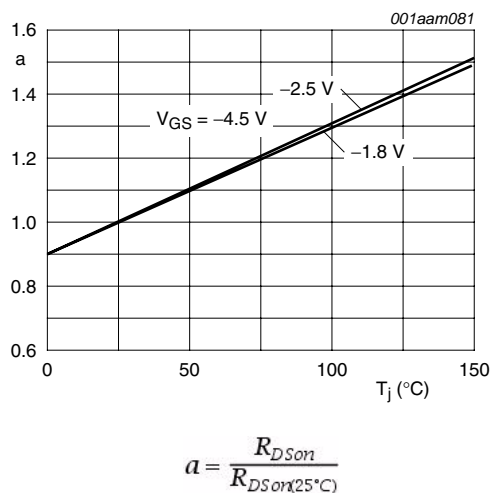


Fig 9. Normalized drain-source on-state resistance factor as a function of junction temperature

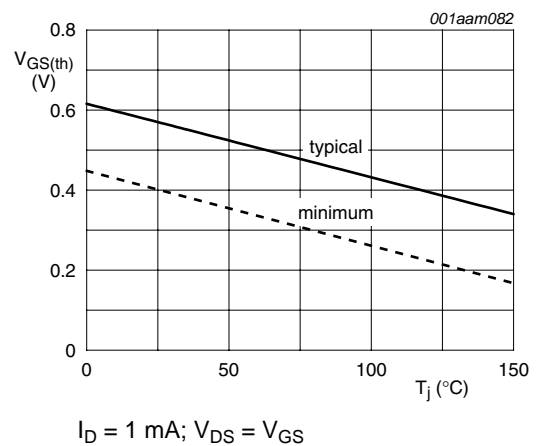


Fig 10. Gate-source threshold voltage as a function of junction temperature

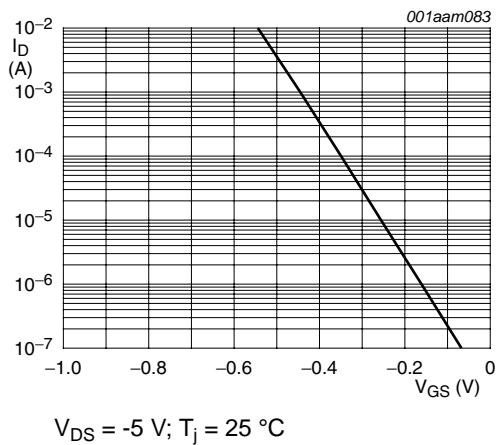


Fig 11. Sub-threshold drain current as a function of gate-source voltage

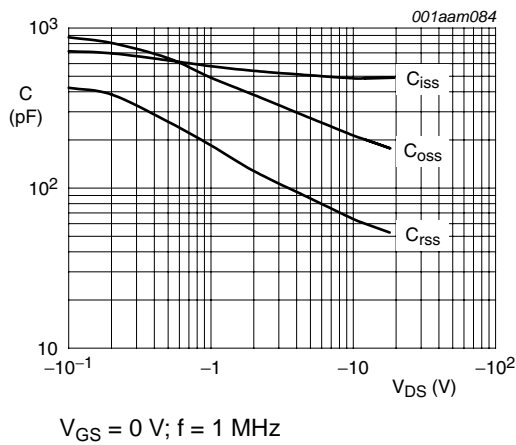


Fig 12. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

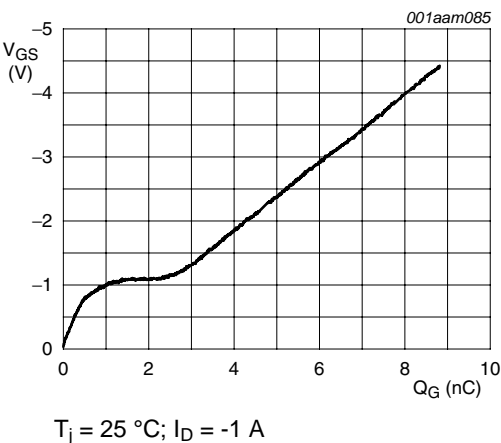


Fig 13. Gate-source voltage as a function of turn-on gate charge; typical values

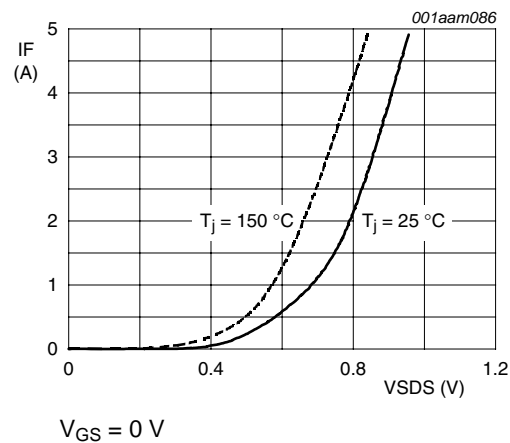


Fig 14. Reverse diode current as a function of reverse diode voltage; typical values

7. Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm SOT96-1

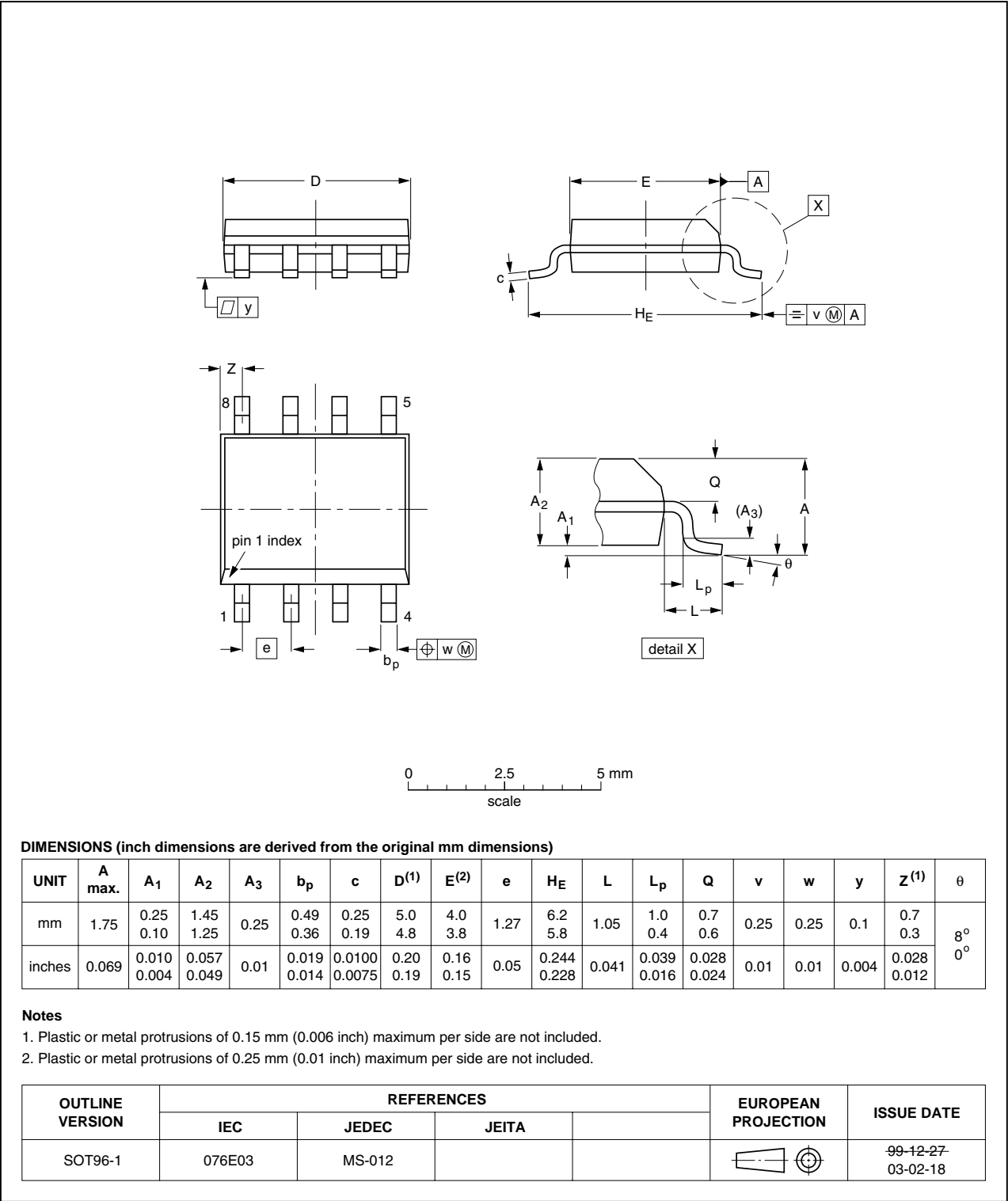


Fig 15. Package outline SOT96-1 (SO8)

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PHK04P02T v.2	20101214	Product data sheet	-	PHK04P02T v.1
Modifications:	<ul style="list-style-type: none">• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.• Legal texts have been adapted to the new company name where appropriate.			
PHK04P02T v.1	20020501	Product specification	-	-

9. Legal information

9.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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